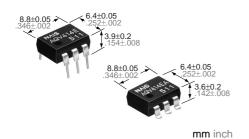




### GU (General Use) Type [1-Channel (Form B) Type]

## PhotoMOS RELAYS



# Cross section of the normally-closed type of power MOS Passivation membrane Source electrode Gate electrode insulating membrane Gate oxidation membrane Orain electrode

# **4. Low-level off state leakage current** The SSR has an off state leakage current of several milliamperes, whereas the PhotoMOS relay has only 100 pA even with the rated load voltage of 400 V.

#### **FEATURES**

#### 1. Low on resistance for normallyclosed type

This has been realized thanks to the builtin MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.

#### 2. Controls low-level analog signals

PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

**3. High sensitivity, low ON resistance** Can control a maximum 0.15 A load current with a 5 mA input current.

#### TYPICAL APPLICATIONS

- Telepone equipment (Dial pulse)
- Measuring equipment

#### **TYPES**

Туре	I/O isolation voltage	Output rating*			Pa	Packing quantity			
				Through hole terminal					
		Load Lo	and Land			Tape and reel packing style			
			Load current	Tube pac	king style	Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side	Tube	Tape and reel
AC/DC type	1,500 V AC	400 V	120 mA	AQV414	AQV414A	AQV414AX	AQV414AZ	1 tube contains 50 pcs. 1 batch contains 500 pcs.	1,000 pcs.

<sup>\*</sup>Indicate the peak AC and DC values.

Note: For space reasons, the package type indicator "X" and "Z" are omitted from the seal.

#### **RATING**

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

	Item	Symbol	Type of connection	AQV414(A)	Remarks	
	LED forward current	lF		50 mA		
Input	LED reverse voltage	VR		3 V		
	Peak forwrd current	IFP		1 A	f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	Pin		75 mW		
	Load voltage (peak AC)	VL		400 V		
		Iι	Α	0.12 A	A connection: Peak AC, DC B,C connection: DC	
Out to the	Continuous load current		В	0.13 A		
Output			С	0.15 A		
	Peak load current	Ipeak		0.3 A	A connection: 100 ms (1 shot), V <sub>L</sub> = DC	
	Power dissipation	Pout		500 mW		
Total power dissipation		P⊤		550 mW		
I/O isolation voltage		Viso		1,500 V AC		
Temperature limits	Operating	Topr		-40°C to +85°C -40°F to +185°F	Non-condensing at low temperatures	
	Storage	Tstg		-40°C to +100°C -40°F to +212°F		

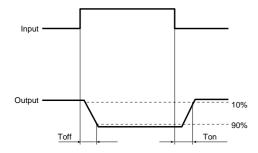
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

	m		Symbol	Type of connection	AQV414(A)	Condition		
	LED operate (OFF) current		Typical	Foff	_	1.0 mA	I∟= 120 mA	
lanut			Maximum			3.0 mA		
	LED reverse (ON) current		Minimum	Fon	_	0.4 mA	IL= 120 mA	
Input			Typical			0.95 mA	IL= 120 MA	
	LED dropout voltage		Typical	M V <sub>F</sub>	_	1.14 V (1.25 V at I <sub>F</sub> = 50 mA)	I <sub>F</sub> = 5 mA	
			Maximum			1.5 V		
	On resistance		Typical	Ron	А	26 Ω	I <sub>F</sub> = 0 mA I <sub>L</sub> = 120 mA Within 1 s on time	
			Maximum			50 Ω		
			Typical	Ron	В	20 Ω	I <sub>F</sub> = 0 mA I <sub>L</sub> = 120 mA Within 1 s on time	
Output			Maximum			25 Ω		
·			Typical	Ron	С	10 Ω	I <sub>F</sub> = 0 mA I <sub>L</sub> = 120 mA Within 1 s on time	
			Maximum			12.5 Ω		
	Off state le	akage current	Maximum	Leak	_	1 μΑ	I <sub>F</sub> = 5 mA V <sub>L</sub> = 400 V	
	Switching speed	Operate (OFF) time*	Typical	Toff	_	0.47 ms	IF = 0 mA $\rightarrow$ 5 mA IL = 120 mA	
			Maximum			1.0 ms		
		Reverse (ON) time*	Typical	Ton	_	0.28 ms	I <sub>F</sub> = 5 mA → 0 mA I <sub>L</sub> = 120 mA	
Transfer			Maximum			1.0 ms		
characteristics	1/0		Typical	_		0.8 pF	f = 1 MHz	
	I/O capacit	ance	Maximum	Ciso	-	1.5 pF	V <sub>B</sub> = 0	
	Initial I/O is resistance	olation	Minimum	Riso	_	1,000 ΜΩ	500 V DC	

Note: Recommendable LED forward current IF= 5 mA.

\*Operate/Reverse time

For type of connection, see Page 445.



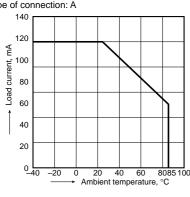
- **■** For Dimensions, see Page 440.
- For Schematic and Wiring Diagrams, see Page 445.
- For Cautions for Use, see Page 449.

#### REFERENCE DATA

1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F

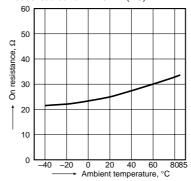
Type of connection: A



2. On resistance vs. ambient temperature char-

Measured portion: between terminals 4 and 6; LED current: 0 mA;

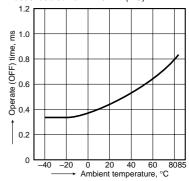
Continuous load current: 120 mA (DC)



3. Operate (OFF) time vs. ambient temperature characteristics

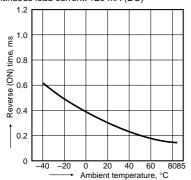
LED current: 5mA; Load voltage: 400 V (DC);

Continuous load current: 120 mA (DC)



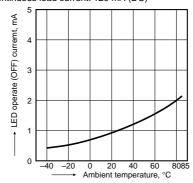
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



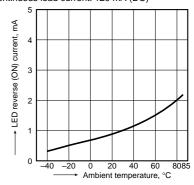
5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



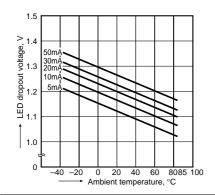
6. LED reverse (ON) current vs. ambient temperature characteristics

Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



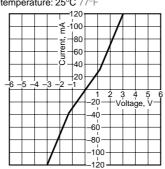
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



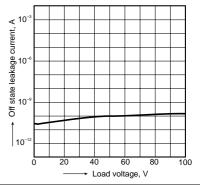
8. Voltage vs. current characteristics of output at MOS portion

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



9. Off state leakage current

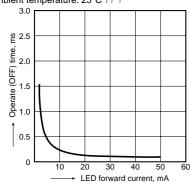
Measured portion: between terminals 4 and 6; LED current: 5 mA; Ambient temperature: 25°C 77°F



10. LED forward current vs. operate (OFF) time characteristics

Measured portion: between terminals 4 and 6; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC);

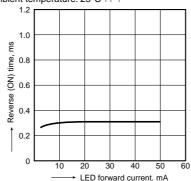
Ambient temperature: 25°C 77°F



11. LED forward current vs. reverse (ON) time characteristics

Measured portion: between terminals 4 and 6; Load voltage: 400 V (DC);

Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



12. Applied voltage vs. output capacitance characteristics

Measured portion: between terminals 4 and 6; Frequency: 1 MHz; Ambient temperature: 25°C 77°F

